

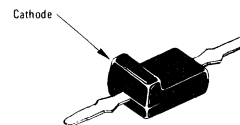
MPN3411 (SILICON)

PIN ATTENUATOR DIODE

...designed primarily as a general purpose attenuator diode. Supplied in popular low-inductance, Mini-L plastic package for low cost, high-volume consumer and industrial requirements.

- Rugged PIN Structure Coupled with Wirebond Construction for Optimum Reliability
- Characterization of Forward Resistance @ 5, 20, 50 and 100 MHz for Greater Design Flexibility
- Low Inductance Mini-L Package
- Mini-L Ridge Clearly Identifies Cathode Lead for Easy Handling and Mounting
- Can be used for AGC in T and Pi configurations.

SILICON PIN ATTENUATOR DIODE



MAXIMUM RATINGS

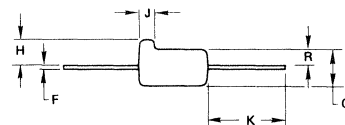
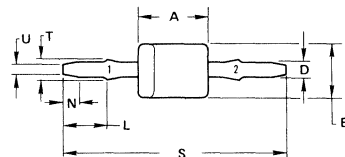
| Rating | Symbol | Value | Unit |
|---|-----------|-------------|----------------------------|
| Reverse Voltage | V_R | 25 | Volts |
| Forward Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_F | 400 4.0 | mW mW/ $^\circ\text{C}$ |
| Junction Temperature | T_J | +125 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -65 to +150 | $^\circ\text{C}$ |

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|-------------|-----|-----|----------|-------|
| Reverse Breakdown Voltage ($I_R = 10 \mu\text{A}$) | $V_{(BR)R}$ | 25 | 100 | — | Volts |
| Diode Capacitance (Note 1) ($V_R = 20 \text{ Vdc}$, $f = 100 \text{ MHz}$) | C_T | — | — | 0.45 | pF |
| Forward Resistance ($I_F = 10 \text{ mA}$, $f = 100 \text{ MHz}$) | R_F | — | — | 10 15 | Ohms |
| Series Inductance (Note 2) ($f = 250 \text{ MHz}$) (Measured at Lead Stop $\approx 1/8"$) | L_S | — | 3.0 | — | nH |
| Case Capacitance ($f = 1.0 \text{ MHz}$) | C_C | — | 0.1 | — | pF |

NOTES

- C_T is measured using a capacitance bridge (Boonton Electronics Model 75A or equivalent).
- L_S is measured on a package having a short instead of a die, using an impedance bridge (Boonton Radio Model 250A RX Meter).



PIN 1, CATHODE
2 ANODE

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 3.86 | 4.11 | 0.152 | 0.162 |
| B | 2.92 | 3.18 | 0.115 | 0.125 |
| C | 1.91 | 2.16 | 0.075 | 0.085 |
| D | 0.64 | 0.89 | 0.025 | 0.035 |
| E | 0.08 | 0.18 | 0.003 | 0.007 |
| F | 1.30 | 1.55 | 0.051 | 0.061 |
| G | 0.64 | 0.89 | 0.025 | 0.035 |
| H | 4.06 | 4.32 | 0.160 | 0.170 |
| I | 2.36 | 2.62 | 0.093 | 0.103 |
| J | 1.12 | 1.37 | 0.044 | 0.054 |
| K | 0.79 | 1.04 | 0.031 | 0.041 |
| L | 11.99 | 12.75 | 0.472 | 0.502 |
| M | 1.14 | 1.40 | 0.045 | 0.055 |
| N | 0.43 | 0.69 | 0.017 | 0.027 |

CASE 226

TYPICAL ELECTRICAL CHARACTERISTICS

FORWARD RESISTANCE versus CURRENT

FIGURE 1 — MPN3411

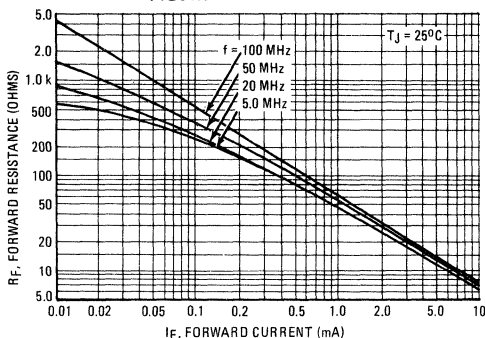


FIGURE 2 — MPN3412

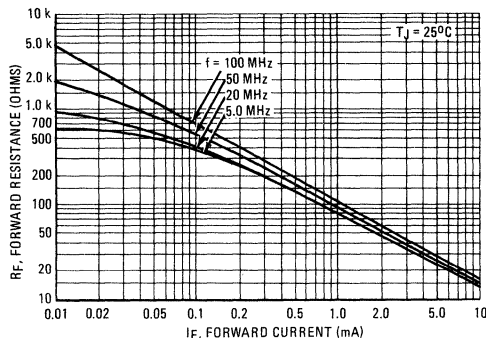


FIGURE 3 — FREQUENCY versus CAPACITANCE

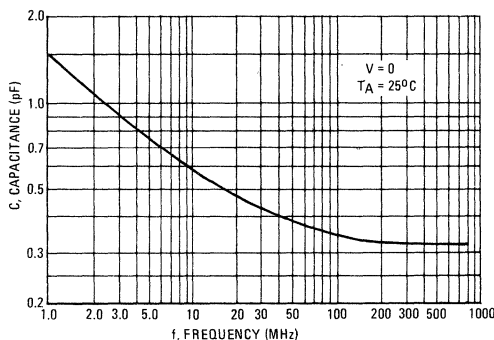
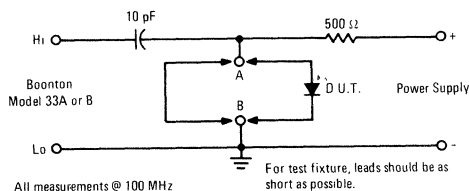


FIGURE 4 — FORWARD RESISTANCE TEST METHOD



To measure forward resistance, a 10 pF capacitor is used to reduce the forward capacitance of the circuit and to prevent shorting of the external power supply through the bridge. The small signal from the bridge is prevented from shorting through the power supply by the 500-ohm resistor. The resistance of the 10 pF capacitor can be considered negligible for this measurement.

1. The RF Admittance Bridge (Boonton 33A or B) must be initially balanced, with the test circuit connected to the bridge test terminals. The conductance scale will be set at zero and the capacitance scale will be set at 120 pF, as required when using the 100 MHz test coil.

2. Use a short length of wire to short the test circuit from point "A" to "B". Then connect the power supply providing 10 mA of bias current to the test circuit.
3. Adjust the capacitance scale arm of the bridge and the "G" zero control for a minimum null on the "null meter". The null occurs at approximately 130 pF.
4. Replace the wire short with the device to be tested. Bias the device to a forward conductance state of 10 mA.
5. Obtain a minimum null on the "null meter", with the capacitance and conductance scale adjustment arms.
6. Read conductance (G) direct from the scale. Now read the capacitance value from the scale (≈ 130 pF) and subtract 120 pF which yields capacitance (C). The forward resistance (R_F) can now be calculated from:

$$R_F = \frac{KG}{C^2}$$

Where:

G — in micromhos, K — frequency dependent constant — Boonton 75A instruction manual.
C — in pF,
 R_F — in ohms